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Processing and characterization of a free-standing bulk polycrystalline GaN layer

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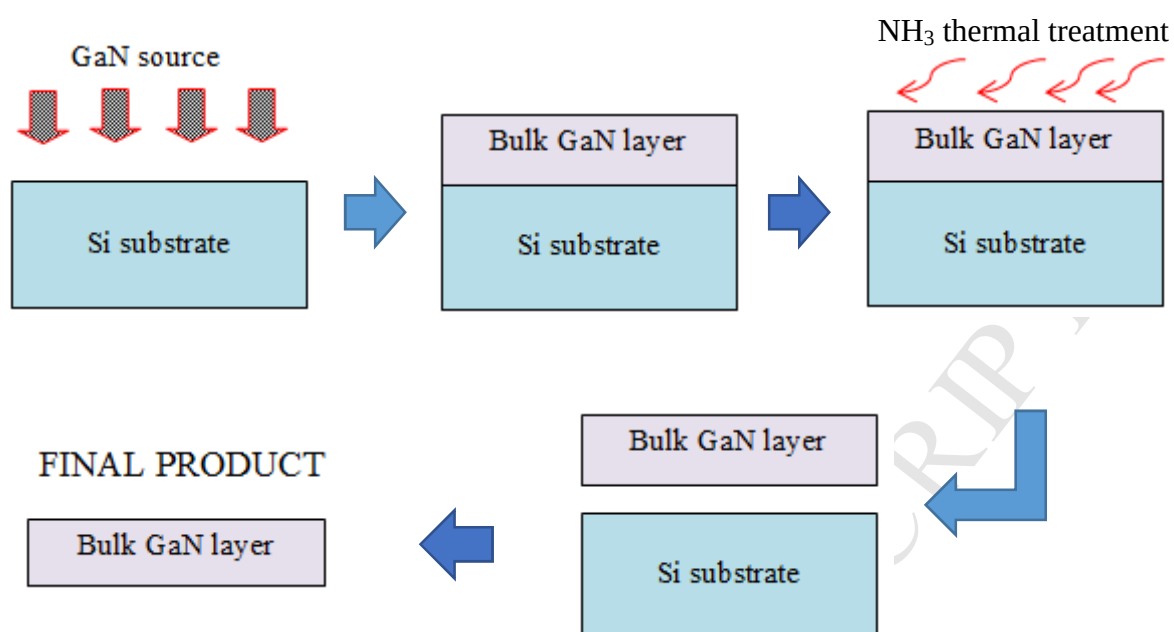
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